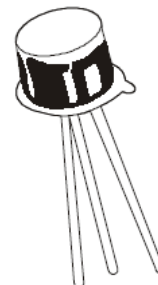


Small Signal General Purpose Transistors (NPN)

Features

- Switching and Linear Application
DC and VHF Amplifier Application
- RoHS Compliant



TO-18



Mechanical Data

Case:	TO-18, Metal can package
Terminals:	Solderable per MIL-STD-202, Method 208
Weight:	0.35 grams

Maximum Ratings ($T_{Ambient}=25^{\circ}C$ unless noted otherwise)

Symbol	Description	2N2221A	2N2222A	Unit
	Marking Code	2N2221A	2N2222A	
V_{CEO}	Collector-Emitter Voltage	40		V
V_{CBO}	Collector-Base Voltage	75		V
V_{EBO}	Emitter-Base Voltage	6.0		V
I_C	Collector Current Continuous	800		mA
P_D	Power Dissipation at $T_A=25^{\circ}C$	500		mW
	Derate above $25^{\circ}C$	2.28		mW/ $^{\circ}C$
P_D	Power Dissipation at $T_C=25^{\circ}C$	1.2		W
	Derate above $25^{\circ}C$	6.85		mW/ $^{\circ}C$
T_J, T_{STG}	Operation and Storage Junction Temperature Range	-65 to +200		$^{\circ}C$

Small Signal General Purpose Transistors (NPN)

2N2221A/2N2222A

Electrical Characteristics ($T_{Ambient}=25^{\circ}\text{C}$ unless noted otherwise)

Symbol	Description	2N2221A		2N2222A		Unit	Conditions
		Min.	Max.	Min.	Max.		
V_{CEO}	Collector-Emitter Voltage	40	-	40	-	V	I _C =10mA, I _B =0
V_{CBO}	Collector-Base Voltage	75	-	75	-	V	I _C =10μA, I _E =0
V_{EBO}	Emitter-Base Voltage	6.0	-	6.0	-	V	I _E =10μA, I _C =0
V_{CE(sat)} *	Collector Emitter Saturation Voltage	-	0.3	-	0.3	V	I _C =150mA, I _B =15mA
		-	1.0	-	1.0		I _C =500mA, I _B =50mA
V_{BE(sat)} *	Base Emitter Saturation Voltage	-	0.6 -1.2	-	0.6 -1.2	V	I _C =150mA, I _B =15mA
		-	2.0	-	2.0		I _C =500mA, I _B =50mA
I_{CBO}	Collector Cut-Off Current	-	10	-	10	nA	V _{CB} =60V, I _E =0
		-	10	-	10	μA	T _A =150°C V _{CB} =60V, I _E =0
I_{CEX}	Collector-Cut-off Current	-	10	-	10	nA	V _{CE} =60V, V _{EB} =3V
I_{EBO}	Emitter Cut-Off Current	-	10	-	10	nA	V _{EB} =3V, I _C =0
I_{BL}	Base Cut-Off Current	-	20	-	20	nA	V _{CE} =60V, V _{EB} =3V
h_{FE}	D.C. Current Gain	20	-	35	-		V _{CE} =10V, I _C =0.1mA
		25	-	50	-		V _{CE} =10V, I _C =1mA
		35	-	75	-		V _{CE} =10V, I _C =10mA
		15	-	35	-		T _A =55°C V _{CE} =10V, I _C =10mA
		40	120	100	300		V _{CE} =10V, I _C =150mA
		20	-	50	-		V _{CE} =1V, I _C =150mA
		25	-	40	-		V _{CE} =10V, I _C =500mA
h_{fe}	Small Signal Current Gain	30	150	50	300		V _{CE} =10V, I _C =1mA f=1KHz,
		50	300	75	375		V _{CE} =10V, I _C =10mA f=1KHz,
h_{ie}	Input Impedance	1.0	3.5	2.0	8.0	kΩ	V _{CE} =10V, I _C =1mA f=1KHz,
		0.2	1.0	0.25	1.25		V _{CE} =10V, I _C =10mA f=1KHz,
h_{re}	Voltage Feedback Ratio	-	5.0	-	8.0	x10 ⁻⁴	V _{CE} =10V, I _C =1mA f=1KHz,
		-	2.5	-	4.0		V _{CE} =10V, I _C =10mA f=1KHz,

Small Signal General Purpose Transistors (NPN)

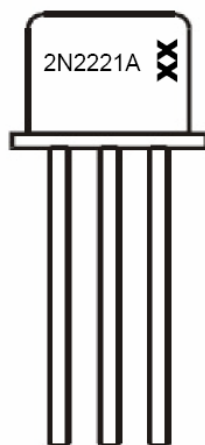
2N2221A/2N2222A

Symbol	Description	2N2221A		2N2222A		Unit	Conditions
		Min.	Max.	Min.	Max.		
h_{oe}	Output Admittance	3.0	15	5.0	35	$\mu\Omega$	VCE=10V, IC=1mA f=1KHz,
		10	100	25	200		VCE=10V, IC=10mA f=1KHz,
rb'Cc	Collector-Base Time Constant	-	150	-	150	pS	VCB=20V, IE=20mA f=31.8MHz,
Re(hie)	Real Part Common-Emitter High Frequency Input Impedance	-	60	-	60	Ω	VCE=20V, IC=20mA f=300MHz
NF	Noise Figure	-	-	-	4.0	dB	VCE=10V, IC=100 μ A, Rs=1K Ω , f=1KHz
f_T	Transistors Frequency	250	-	300	-	MHz	VCE=20V, IC=20mA, f=100MHz
Cob	Output Capacitance	-	8.0	-	8.0	pF	VCB=10V, IE=0 f=100KHz,
Cib	Input Capacitance	-	25	-	25	pF	VEB=0.5V, IC=0 f=100KHz,
td	Delay Time	-	10	-	10	nS	VCC=30V, VBE=0.5V IC=150mA, IB1=15mA
tr	Rise Time	-	25	-	25	nS	
ts	Storage Time	-	225	-	225	nS	VCC=30V, IC=150mA IB1=IB2=15mA
tf	Fall Time	-	60	-	60	nS	

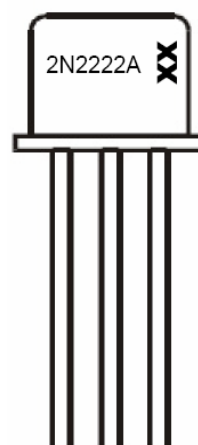
*Pulse Condition: Pulse Width=300 μ s, Duty Cycle=2%

Marking Information:

2N2221A



2N2222A



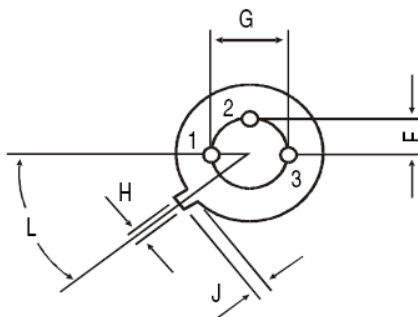
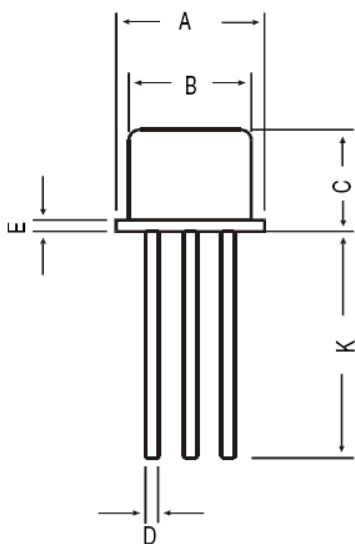
XX = Date Code

Small Signal General Purpose Transistors (NPN)

2N2221A/2N2222A

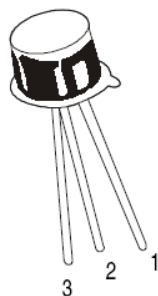
Dimensions in mm

TO-18



All dimensions in mm.

DIM	MIN	MAX
A	5.24	5.84
B	4.52	4.97
C	4.31	5.33
D	0.40	0.53
E	—	0.76
F	—	1.27
G	—	2.97
H	0.91	1.17
J	0.71	1.21
K	12.70	—
L	45 DEG	



PIN CONFIGURATION

- 1. EMITTER
- 2. BASE
- 3. COLLECTOR

Packing Information:

Standard Pack	
Details	Net Weight/Qty.
1k/polybag	350gm/1k pcs

Small Signal General Purpose Transistors (NPN)

2N2221A/2N2222A

Carton Information:

Inner Carton Box	
Size	Qty.
3' x 7.5' x 7.5'	5k pcs

Outer Carton Box		
Size	Qty.	Gross Weight
17' x 15' x 13.5'	80k pcs	34kgs

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